

L Number	Hits	Search Text	DB	Time stamp
1	26626	semiconductor and (tft or (thin adj film adj transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/06 08:46
2	2485	(semiconductor and (tft or (thin adj film adj transistor))) and gate and drain and source and offset	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/06 08:47
3	341	((semiconductor and (tft or (thin adj film adj transistor))) and gate and drain and source and offset) and sidewall	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/06 08:47
4	248	((((semiconductor and (tft or (thin adj film adj transistor))) and gate and drain and source and offset) and sidewall) and (gate adj electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/06 08:48
5	88	(((((semiconductor and (tft or (thin adj film adj transistor))) and gate and drain and source and offset) and sidewall) and (gate adj electrode)) and (offset adj region)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/06 08:48